

# Pb RoHS COMPLIANCE



# **Features**

- Low power loss, high efficiency
- → High current capability, Low forward voltage drop.
- Plastic material used carries Underwriters Laboratory Classification 94V-0
- ♦ High surge current capabilitry
- ♦ Qualified as per AEC-Q101
- ♦ Guard-ring for transient protection
- For use in low voltage, high frequency inventor, freewheeling, and polarity protection application
- ♦ High temperature soldering guaranteed: 260°C/10S/.375"(9.5mm) lead lengths 5 lbs tension

## **Mechanical Data**

- ♦ Case: ITO-220AB
- Terminals: Pure tin plated leads, solderable per MIL-STD-202, Method 208 guaranteed
- ♦ Polarity: As marked
- ♦ Weight: 1.7 grams
- ♦ Mounting Torque:5 in-lbs. max.
- ♦ Mounting position:Any

# **Maximum Ratings and Electrical Characteristics**

Rating at 25  $^{\circ}$ C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

# .185(4.7) MAX .134(3.4)DIA .112(2.85) .100(2.55) .272(6.9) .248(6.3) .104(2.65) .104(2.65) .030(0.76) .030(0.76) .035(0.9) .035(0.9) .030(0.76)

.100(2.54) TY

PIN1 0 N

PIN 3 O-N

.105(2.67)

WW

Low VF Isolated 10.0Amp Schottky Barrier Rectifier ITO-220AB

## **Dimensions in inches and (millimeters)**



## Marking Diagram

PIN 2

.100(2.54) TYP

.095(2.41)

MBRF10LXXXCT = Specific Device Code
G = Green Compound
Y = Year Code

= Work Week Code

MBRF10L100CT

Parameter	Symbol	MBRF10L100CT		Unit
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	100		V
Maximum RMS Voltage	$V_{RMS}$	70		V
Maximum DC blocking voltage	$V_{DC}$	100		V
Maximum Average Forward Rectified Current	I <sub>F(AV)</sub>	10		Α
Peak Repetitive Forward Current (Rated VR, Square Wave, 20KHz)	I <sub>F(RMS)</sub>	10		А
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load	I <sub>FSM</sub>	120		А
Peak Repetitive Reverse Surge Current (Note 1)	I <sub>RRM</sub>	1		Α
Maximum Instantaneous Forward Voltage (Pulse test: tp=300us, $\delta$ < 1%) @ 5A / Ta=25 $^{\circ}$ C @ 5A / Ta=125 $^{\circ}$ C @ 10A / Ta=25 $^{\circ}$ C @ 10A / Ta=125 $^{\circ}$ C	V <sub>F</sub>	TYP. 0.73 0.59 0.82 0.66	Max. 0.76 0.65 0.85 0.71	V
Maximum Reverse Current (Pulse test: tp=300us, $\delta$ < 1%) Ta=25 $^{\circ}\mathrm{C}$ Ta=125 $^{\circ}\mathrm{C}$	I <sub>R</sub>	TYP. 0.3 0.5	Max. 20 15	uA mA
Voltage rate of change (rated $V_R$ )	dV/dt	10,000		V/uS
Typical Junction Capacitance (Note 2)	Cj	185		pF
Typical Thermal Resistance (Note 3)	R <sub>eJC</sub>	5.5		°C/W
Operating Temperature Range	TJ	-55 to + 150		οС
Storage Temperature Range	T <sub>STG</sub>	-55 to + 150		οС

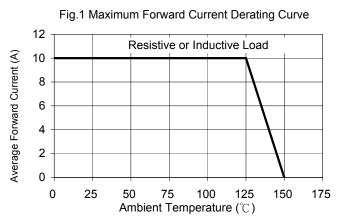
Note1: 2.0uS Pulse Width, F=1.0KHz, Continues 10 cycles

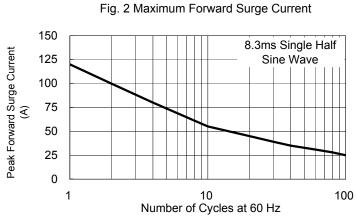
Note2: Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.

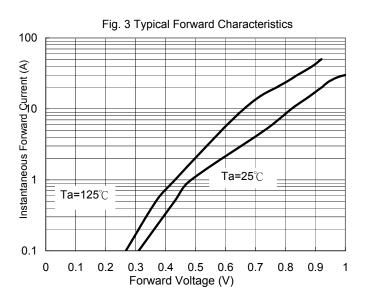
Note3: Mount on Heatsink Size of 4" x 6" x 0.25" Al-Plate

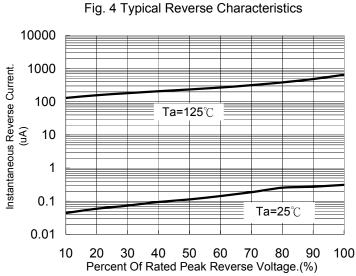


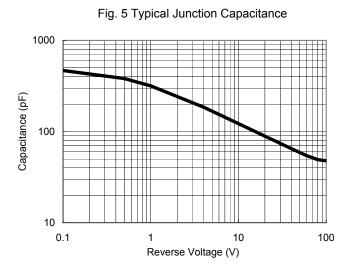
# RATINGS AND CHARACTERISTIC CURVES (MBRF10L100CT)











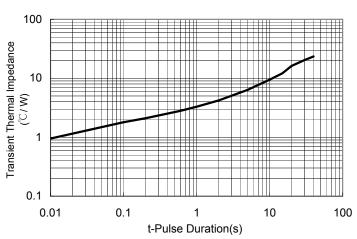


Fig. 6 Typical Transient Thermal Impedance